LMC7101Q-Q1
レール ツー レール入出力、車載用、超小型、低消費電力オペアンプ

1 特長

- 車載アプリケーション用に AEC-Q100 認定済み:
  - 温度:-40℃～+125℃、T_A
- 超小型の 5 ピン SOT-23 パッケージによりスペースを削減できます。標準的な回路レイアウトは 8 ピン SOIC 設計の半分のスペースを占有します
- 2.7V、3V、5V、15V 電源について規定
- 電源電流 (標準値):5V で 0.5mA
- 全高調波歪み (標準値):5V で 0.01%
- 1MHz ゲイン帯域幅
- 一般的な LMC6482 および LMC6484 と類似
- レール ツー レール入出力

2 アプリケーション

- モバイル通信
- ノート PC および PDA
- バッテリ駆動製品
- センサ インターフェイス
- 車載用アプリケーション

3 概要

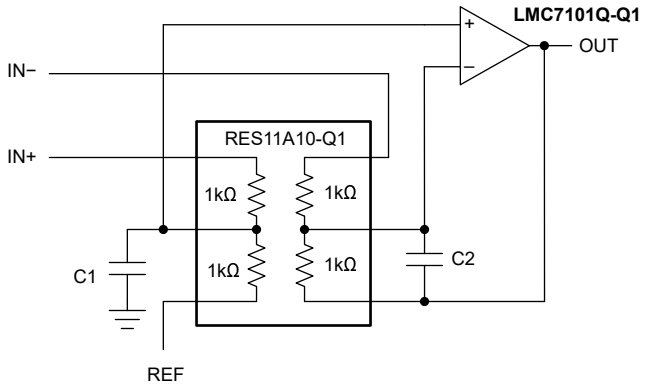
LMC7101Q-Q1 デバイスは高性能な車載用 CMOS オペアンプで、省スペースの 5 ピン SOT-23 小型パッケージで提供されます。この設計により、LMC7101Q-Q1 はスペースと重量の制約が厳しい設計にも最適です。性能は LMC6482 および LMC6484 のシングル アンプと同様で、レール ツー レールの入出力、高い開ループ ゲイン、低歪み、低消費電流を特長としています。

超小型パッケージの主な利点は、スペース制約が厳しいアプリケーションで最も明白です。超小型アンプは必要に応じて基板に配置できるため、基板レイアウトを簡素化できます。

パッケージ情報

部品番号	パッケージ (1)	パッケージ サイズ(2)
LMC7101Q-Q1	DBV (SOT-23、5)	2.9mm × 2.8mm

(1) 詳細については、セクション 10 を参照してください。
(2) パッケージ サイズ (長さ×幅) は公称値であり、該当する場合はピンも含まれます。



RES11A-Q1 を使った差動アンプのアプリケーション

Table of Contents

4 Pin Configuration and Functions

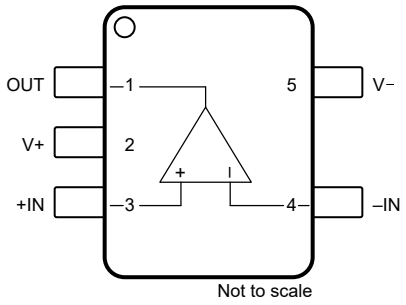


図 4-1. DBV Package, 5-Pin SOT-23 (Top View)

表 4-1. Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	OUT	Output	Output
2	V+	Power	Positive supply
3	+IN	Input	Noninverting input
4	−IN	Input	Inverting input
5	V−	Power	Negative supply

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	MAX	UNIT
	Difference Input voltage		±Supply voltage	V
	Voltage at input and output pins	(V–) – 0.3	(V+) + 0.3	V
V_S	Supply voltage, V_S = (V+) – (V–)		16	V
	Current at input pin	–5	5	mA
	Current at output pin(3)	–35	35	mA
	Current at power supply pin		35	mA
	Lead temperature (soldering, 10s)		260	°C
T_J	Junction temperature(4)		150	°C
T_{stg}	Storage temperature	–65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) If Military/Aerospace specified devices are required, contact the TI Sales Office or Distributors for availability and specifications.
(3) Applies to both single-supply and split-supply operation. Continuous short operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature at 150°C
(4) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$ and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} – T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly into a PC board.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101	±1000	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_S	Supply voltage, V_S = (V+) – (V–)	2.7		15.5	V
T_A	Ambient temperature	–40		125	°C

5.4 Thermal Information

THERMAL METRIC(1)		LMC7101Q-Q1 DBV (SOT-23) 5 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	193.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	128.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	88.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	66.8	°C/W
ψ_{JB}	Junction-to-board characterization parameter	88.6	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.5 Electrical Characteristics for V_S = 2.7V or ±1.35V

at T_A = 25°C, V+ = 2.7V, V– = 0V, V_{CM} = V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.11	±9	mV
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power-supply rejection ratio	V+ = 1.35V to 1.65V, V– = –1.35V to –1.65V, V_{CM} = 0V		45	60		dB
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
INPUT VOLTAGE							
V_{CM}	Common-mode voltage	For CMRR ≥ 47dB	Positive	2.7	3		V
			Negative		0	0	
CMRR	Common-mode rejection	0V ≤ V_{CM} ≤ 2.7V		47	70		dB
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Common-mode input capacitance				3		pF
FREQUENCY RESPONSE							
GBW	Gain bandwidth product				0.6		MHz
SR	Slew rate(1)	V+ = 15V, 10V step, G = 1, R_L = 100kΩ to 7.5V, V_{OUT} = $10V_{PP}$, f = 1kHz			0.7		V/µs
OUTPUT							
V_O	Voltage output swing	Positive rail	R_L = 2kΩ	2.15	2.45		V
			R_L = 10kΩ	2.64	2.68		
		Negative rail	R_L = 2kΩ		0.25	0.5	
			R_L = 10kΩ		0.025	0.06	
POWER SUPPLY							
I_Q	Quiescent current per amplifier				500	810	µA
		T_A = –40°C to +125°C			500	950	

(1) Number specified is the slower of the positive and negative slew rates.

5.6 Electrical Characteristics for V_S = 3V or ±1.5V

at T_A = 25°C, V+ = 3V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.11	±7	mV
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power-supply rejection ratio	V+ = 1.5V to 7.5V, V– = –1.5V to –7.5V, V_{OUT} = V_{CM} = 0V		60	80		dB
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
INPUT VOLTAGE							
V_{CM}	Input common-mode voltage	For CMRR ≥ 47dB	Positive	3	3.3		V
			Negative		0	0	
CMRR	Common-mode rejection	0V ≤ V_{CM} ≤ 3V		47	70		dB
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Common-mode input capacitance				3		pF
OUTPUT							
V_O	Voltage output swing	Positive rail	R_L = 2kΩ	2.6	2.8		V
			R_L = 600Ω	2.5	2.7		
		Negative rail	R_L = 2kΩ		0.2	0.4	
			R_L = 600Ω		0.37	0.6	
POWER SUPPLY							
I_Q	Quiescent current per amplifier				500	810	µA
		T_A = –40°C to +125°C			500	950	

5.7 Electrical Characteristics for V_S = 5V or ±2.5V

at T_A = 25°C, V+ = 5V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.11	±7	mV
		T_A = –40°C to +125°C			±0.11	±9	
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power supply rejection ratio	Positive V+ = 5V to 15V V– = 0V, V_{OUT} = 1.5V		65	82		dB
			T_A = –40°C to +125°C	62	82		
		Negative V+ = –5V to –15V V– = 0V, V_{OUT} = –1.5V		65	82		
			T_A = –40°C to +125°C	62	82		
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
NOISE							
THD	Total harmonic distortion	f = 10kHz, G = – 2V/V, R_L = 10kΩ, V_{OUT} = $4V_{pp}$			0.01		%
INPUT VOLTAGE							
V_{CM}	Input common-mode voltage	To positive rail CMRR > 50dB		5.2	5.3		V
			T_A = –40°C to +125°C	4.8	5.3		
		To negative rail CMRR > 50dB			–0.3	–0.2	
			T_A = –40°C to +125°C		–0.3	0.2	
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤ 5V		52	75		dB
		0.2V ≤ V_{CM} ≤ 4.8V, T_A = –40°C to +125°C		51	74		
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Input capacitance				3		pF
FREQUENCY RESPONSE							
GBW	Gain bandwidth product				1		MHz
SR	Slew rate				1		V/µs
OUTPUT							
V_O	Voltage output swing	Positive rail R_L = 2kΩ		4.7	4.9		V
			T_A = –40°C to +125°C	4.54	4.9		
		Negative rail R_L = 2kΩ			0.1	0.18	
			T_A = –40°C to +125°C		0.1	0.28	
		Positive rail R_L = 600Ω		4.5	4.7		
			T_A = –40°C to +125°C	4.28	4.7		
		Negative rail R_L = 600Ω			0.3	0.5	
			T_A = –40°C to +125°C		0.3	0.8	
I_{SC}	Short-circuit current	Sourcing V_{OUT} = 0V		16	24		mA
			T_A = –40°C to +125°C	9	24		
		Sinking V_{OUT} = 5V		11	19		
			T_A = –40°C to +125°C	5.8	19		
POWER SUPPLY							
I_Q	Quiescent current per amplifier				0.5	0.85	mA
		T_A = –40°C to +125°C			0.5	1	

5.8 Electrical Characteristics for V_S = 15V or ±7.5V

at T_A = 25°C, V+ = 15V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.26		mV
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power-supply rejection ratio	Positive V+ = 5V to 15V, V– = 0V, V_{OUT} = 1.5V		62	82		dB
			T_A = –40°C to +125°C	60	82		
		Negative V+ = –5V to –15V, V– = 0V, V_{OUT} = –1.5V		65	82		
			T_A = –40°C to +125°C	62	82		
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
NOISE							
e_n	Input voltage noise density	f = 1kHz, V_{CM} = 1V			37		nV/√Hz
i_n	Input current noise density	f = 1kHz			6.8		fA/√Hz
THD	Total harmonic distortion	f = 1kHz, G = – 2V/V, R_L = 10kΩ, V_{OUT} = 8.5V_{pp}			0.01		%
INPUT VOLTAGE							
V_{CM}	Input common-mode voltage	To positive rail V+ = 15V, CMRR > 50dB		15.2	15.3		V
			T_A = –40°C to +125°C	14.8	15.3		
		To negative rail V+ = 15V, CMRR > 50dB			–0.3	–0.2	
			T_A = –40°C to +125°C		–0.3	0.2	
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤15V		62	82		dB
		0.2V ≤ V_{CM} ≤ 14.8V, T_A = –40°C to +125°C		60	82		
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Input capacitance				3		pF
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	Sourcing 7.5V < V_O < 12.5V, V_{CM} = 1.5V R_L = 2kΩ to 7.5V		80	340		V/mV
			T_A = –40°C to +125°C	30	340		
		Sinking 2.5V < V_O < 7.5V, V_{CM} = 1.5V R_L = 2kΩ to 7.5V		15	24		
			T_A = –40°C to +125°C	4	24		
		Sourcing, V_{CM} = 1.5V, 7.5V < V_O < 12.5V, R_L = 600Ω		34	300		
		Sinking, V_{CM} = 1.5V, 2.5V < V_O < 7.5V, R_L = 600Ω		6	15		

5.8 Electrical Characteristics for V_S = 15V or ±7.5V (続き)

at T_A = 25°C, V+ = 15V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
FREQUENCY RESPONSE							
GBW	Gain bandwidth product				1.1		MHz
SR	Slew rate(1)	10V step, R_L = 100kΩ to 7.5V V_{OUT} = 10V_{PP}, f = 1kHz		0.5	1.1		V/µs
			T_A = –40°C to +125°C	0.4	1.1		
θ_m	Phase margin				45		°
G_m	Gain margin				10		dB
OUTPUT							
V_O	Voltage output swing	Positive rail R_L = 2kΩ		14.4	14.7		V
			T_A = –40°C to +125°C	14.2	14.7		
		Negative rail R_L = 2kΩ			0.16	0.32	
			T_A = –40°C to +125°C		0.16	0.45	
		Positive rail R_L = 600Ω		13.4	14.1		
			T_A = –40°C to +125°C	12.85	14.1		
		Negative rail R_L = 600Ω			0.5	1	
			T_A = –40°C to +125°C		0.5	1.5	
I_{SC}	Short-circuit current(2)	Sourcing V_{OUT} = 0V		30	50		mA
			T_A = –40°C to +125°C	20	50		
		Sinking V_{OUT} = 12V		30	50		
			T_A = –40°C to +125°C	20	50		
POWER SUPPLY							
I_Q	Quiescent current per amplifier				0.8	1.5	mA
		T_A = –40°C to +125°C			0.8	1.75	

(1) Number specified is the slower of the positive and negative slew rates.
(2) Do not short circuit output to V+ when V+ is greater than 12V or reliability can be adversely affected.

5.9 Typical Characteristics for V_S = 2.7V

at V+ = 2.7V, V– = 0V, and T_A = 25°C (unless otherwise specified)

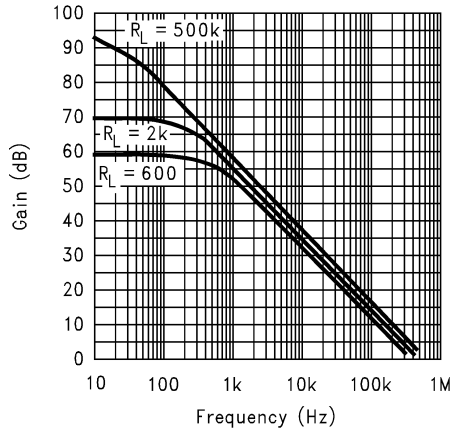


図 5-1. Open-Loop Frequency Response

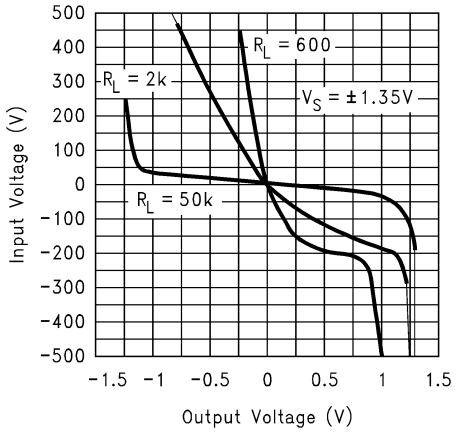


図 5-2. Input Voltage vs Output Voltage

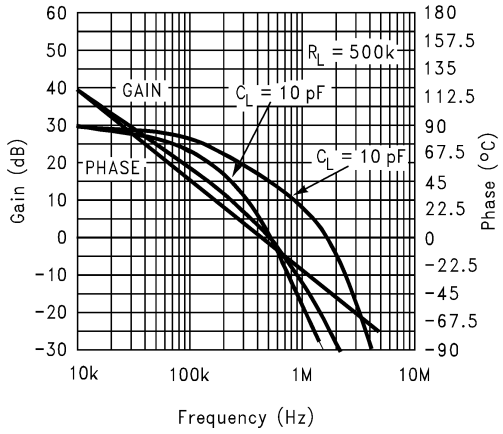


図 5-3. Gain and Phase vs Capacitance Load

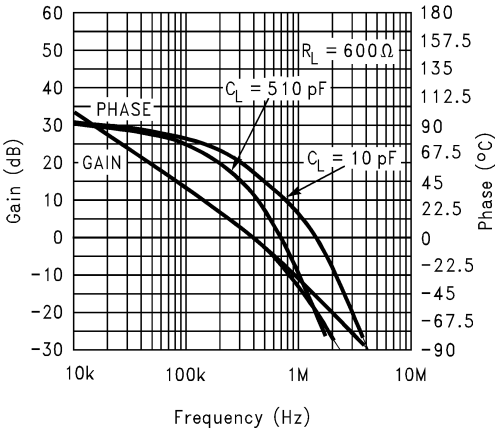


図 5-4. Gain and Phase vs Capacitance Load

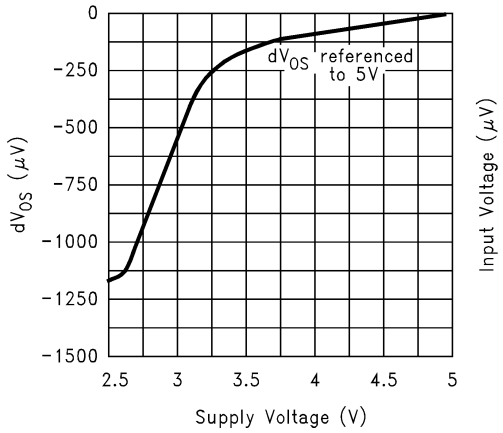
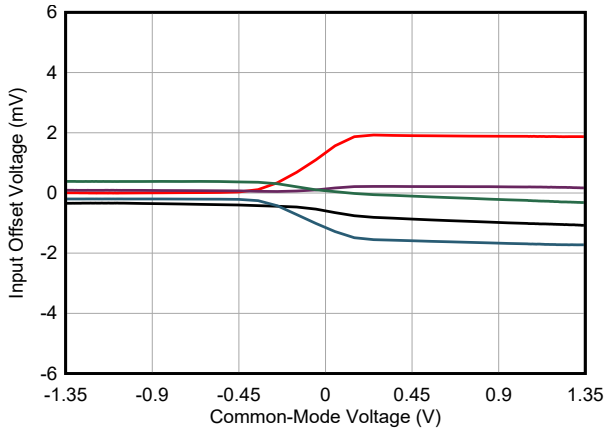


図 5-5. dV_{OS} vs Supply Voltage



5 typical units

図 5-6. Input Offset Voltage vs Common-Mode Voltage

5.9 Typical Characteristics for V_S = 2.7V (continued)

at V+ = 2.7V, V– = 0V, and T_A = 25°C (unless otherwise specified)

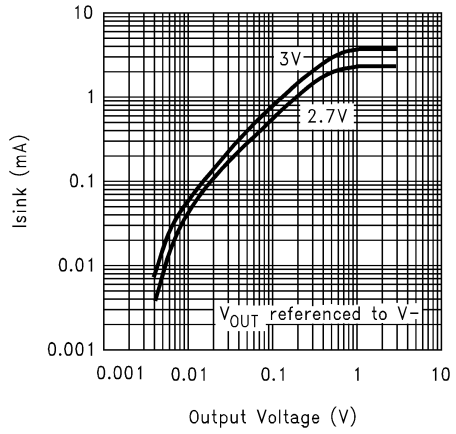


図 5-7. Sinking Current vs Output Voltage

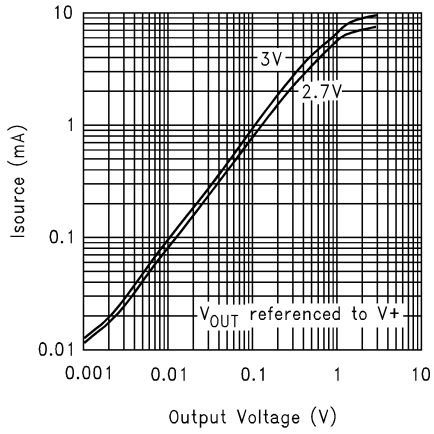


図 5-8. Sourcing Current vs Output Voltage

5.10 Typical Characteristics for V_S = 3V

at V+ = 3V, V– = 0V, and T_A = 25°C (unless otherwise specified)

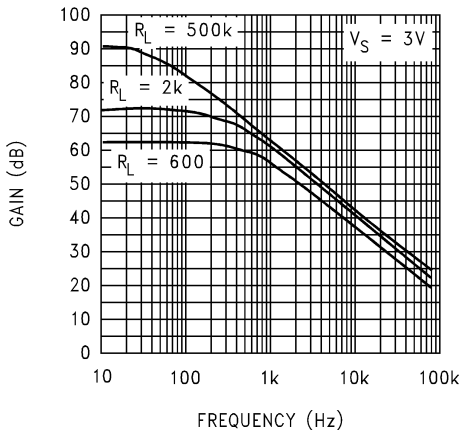


図 5-9. Open-Loop Frequency Response

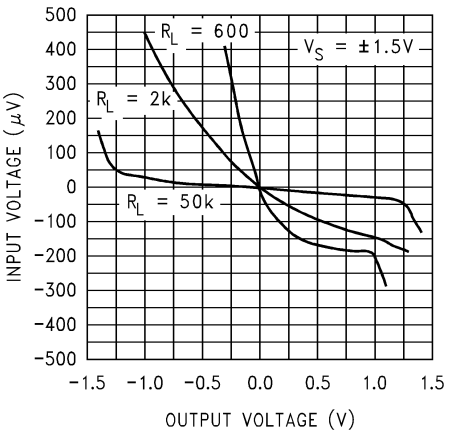


図 5-10. Input Voltage vs Output Voltage

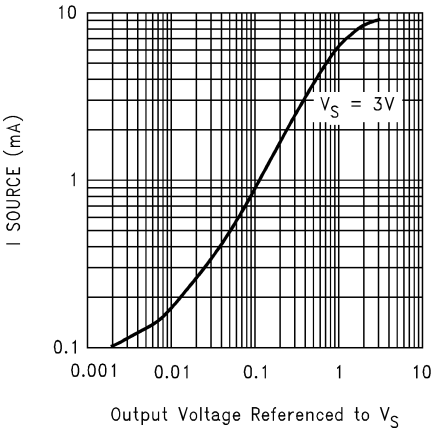


図 5-11. Sourcing Current vs Output Voltage

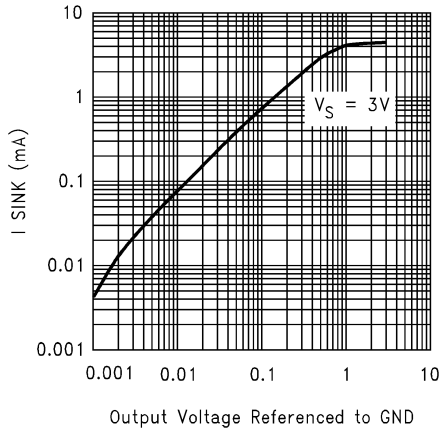


図 5-12. Sinking Current vs Output Voltage

5.11 Typical Characteristics for V_S = 5V

at V+ = 5V, V– = 0V, and T_A = 25°C (unless otherwise specified)

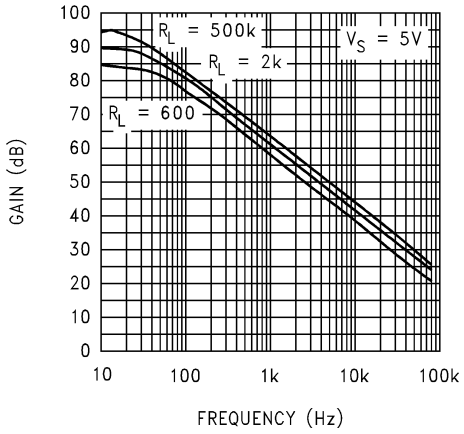


図 5-13. Open-Loop Frequency Response

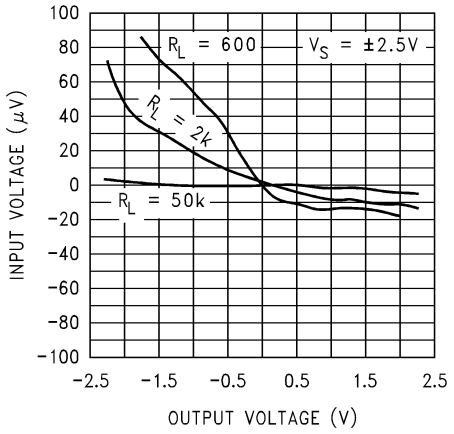


図 5-14. Input Voltage vs Output Voltage

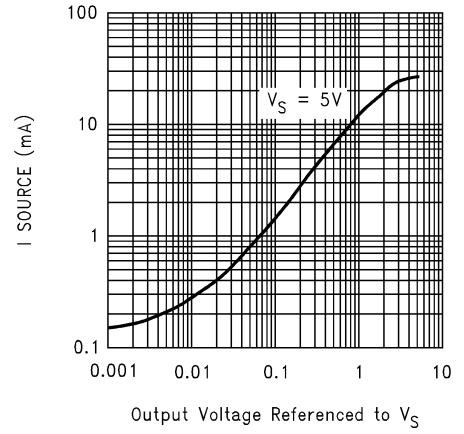


図 5-15. Sourcing Current vs Output Voltage

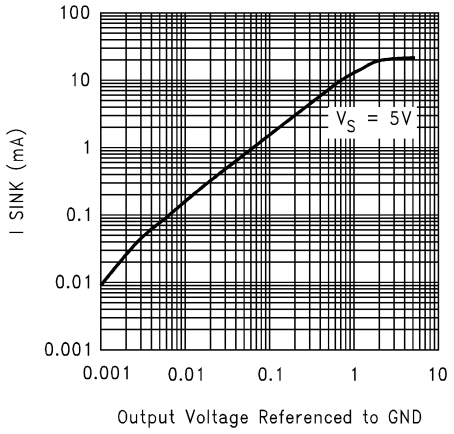


図 5-16. Sinking Current vs Output Voltage

5.12 Typical Characteristics for V_S = 15V

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

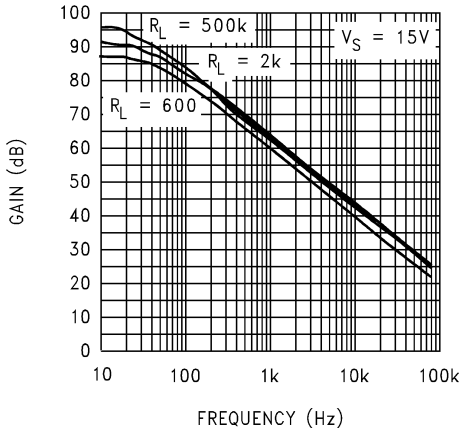


図 5-17. Open-Loop Frequency Response

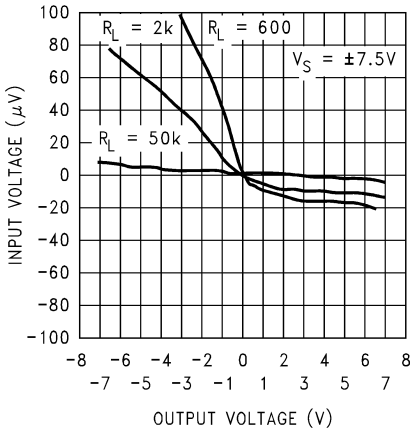


図 5-18. Input Voltage vs Output Voltage

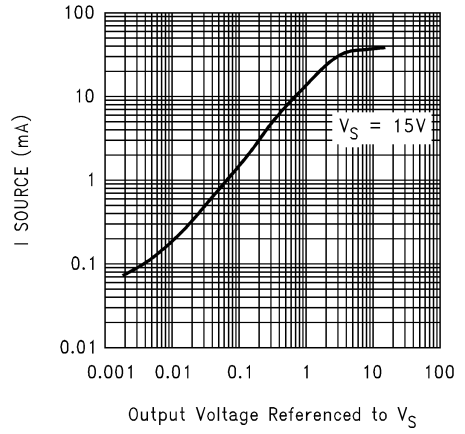


図 5-19. Sourcing Current vs Output Voltage

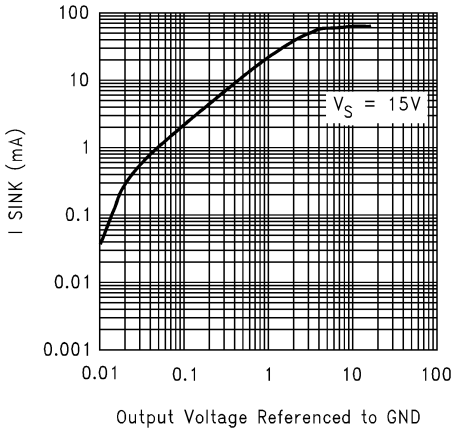


図 5-20. Sinking Current vs Output Voltage

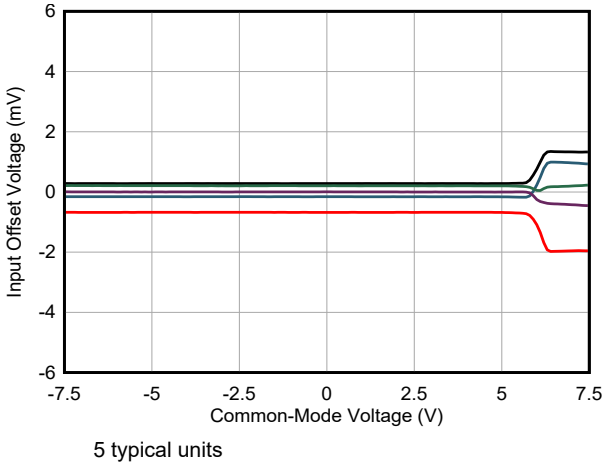


図 5-21. Input Offset Voltage vs Common-Mode Voltage

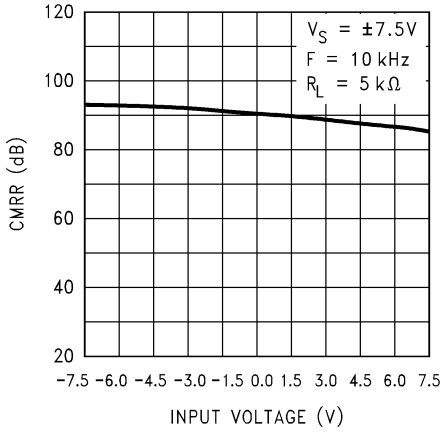


図 5-22. CMRR vs Input Voltage

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

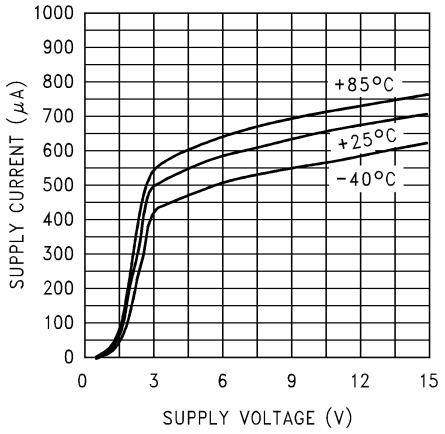


図 5-23. Supply Current vs Supply Voltage

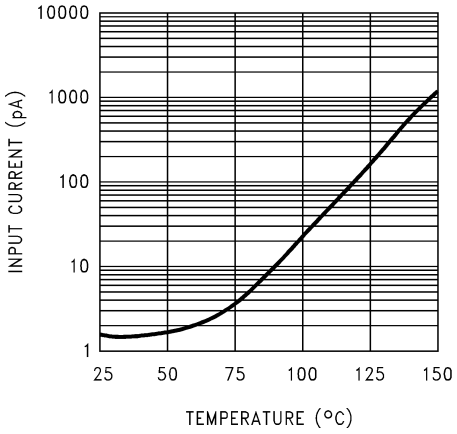


図 5-24. Input Current vs Temperature

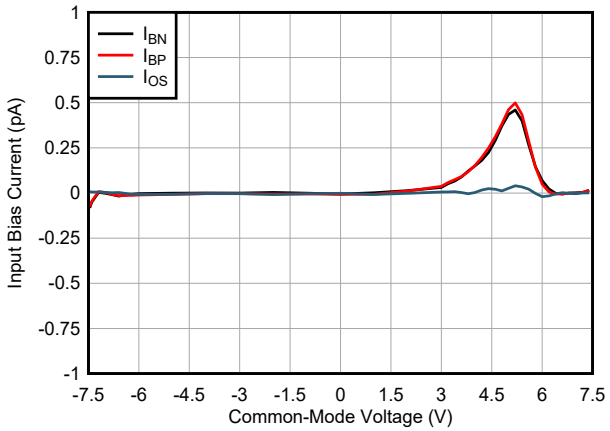


図 5-25. Input Bias Current vs Common-Mode Voltage

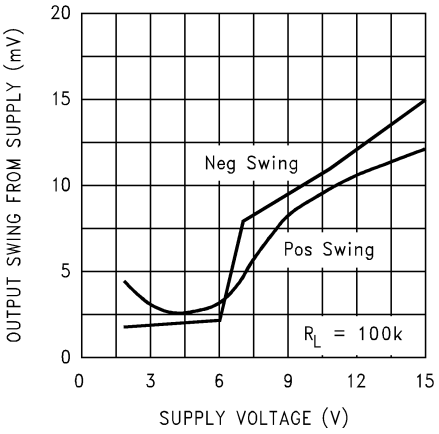


図 5-26. Output Voltage Swing vs Supply Voltage

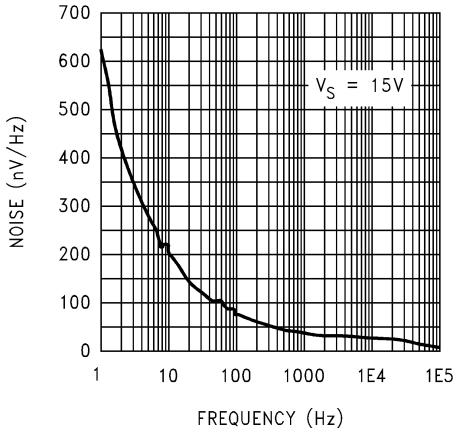


図 5-27. Input Voltage Noise vs Frequency

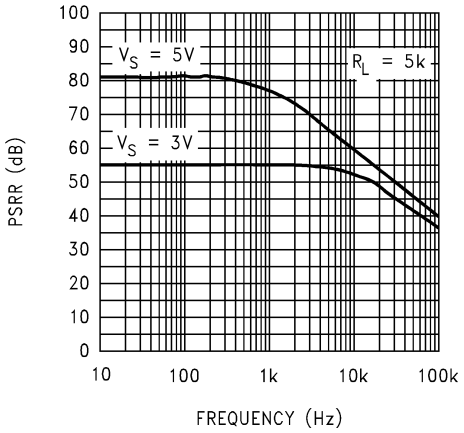


図 5-28. Positive PSRR vs Frequency

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

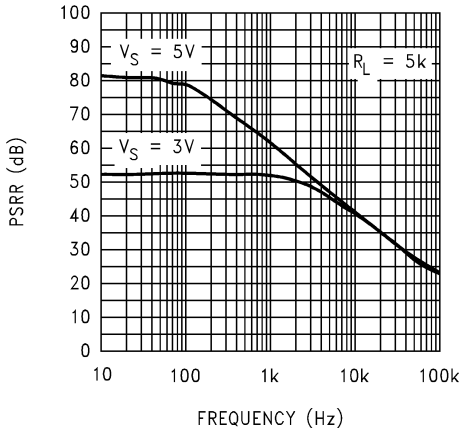


図 5-29. Negative PSRR vs Frequency

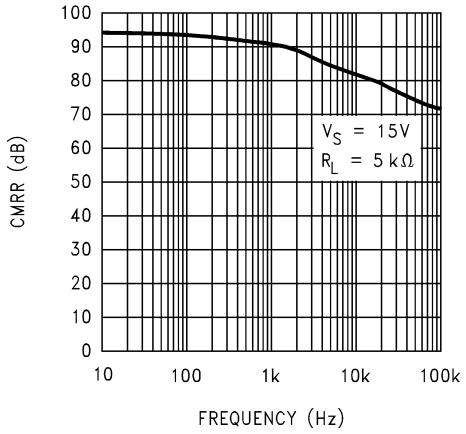


図 5-30. CMRR vs Frequency

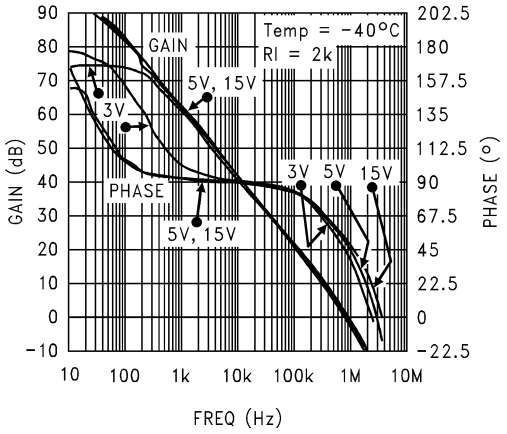


図 5-31. Open-Loop Frequency Response at –40°C

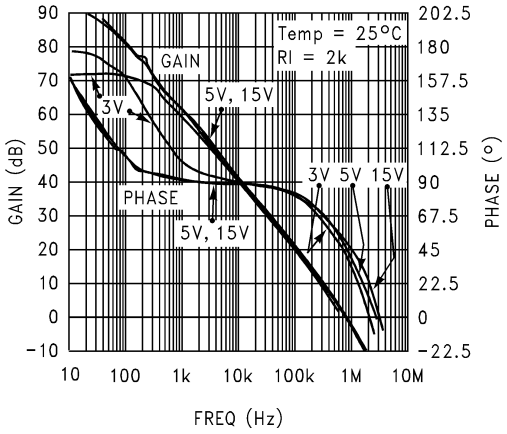


図 5-32. Open-Loop Frequency Response at 25°C

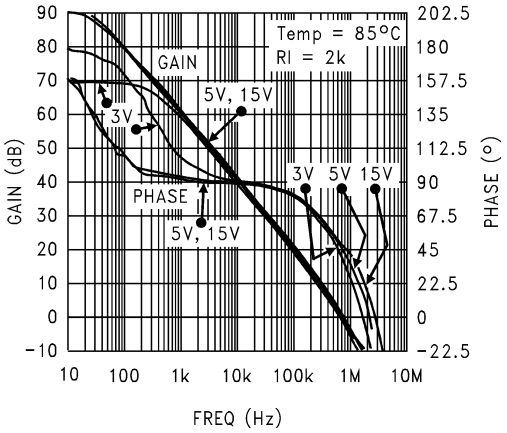


図 5-33. Open-Loop Frequency Response at 85°C

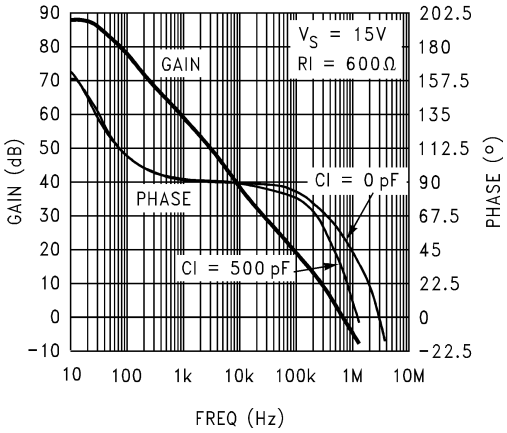


図 5-34. Gain and Phase vs Capacitive Load

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

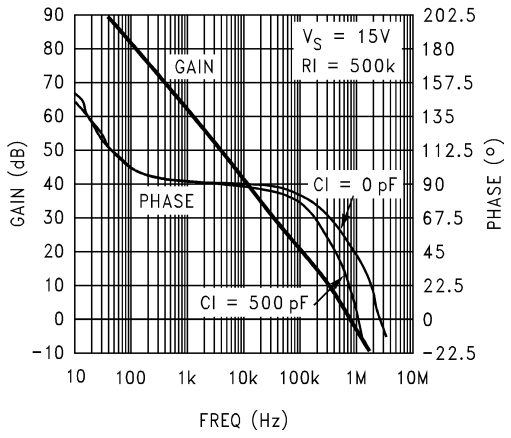


図 5-35. Gain and Phase vs Capacitive Load

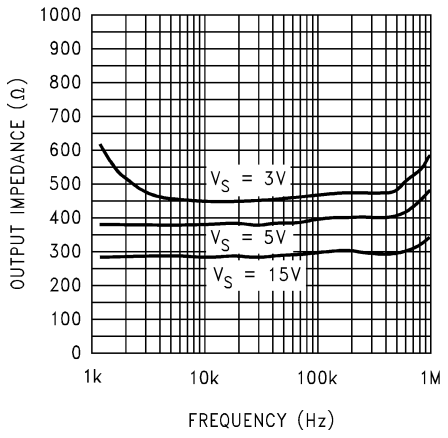


図 5-36. Output Impedance vs Frequency

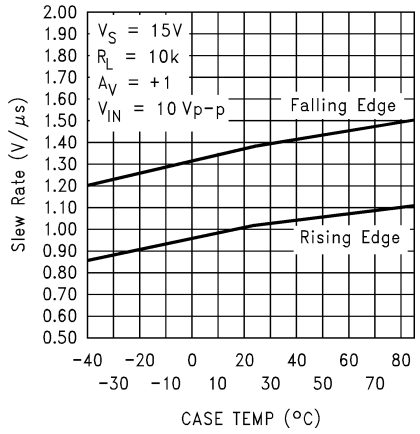


図 5-37. Slew Rate vs Temperature

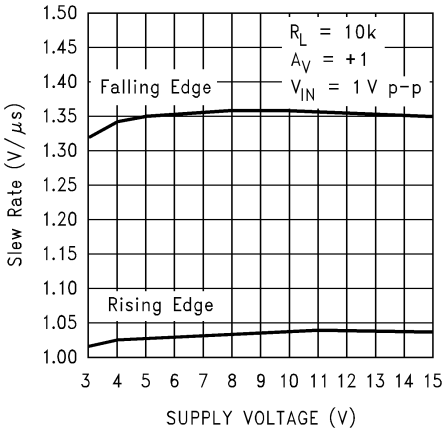


図 5-38. Slew Rate vs Supply Voltage

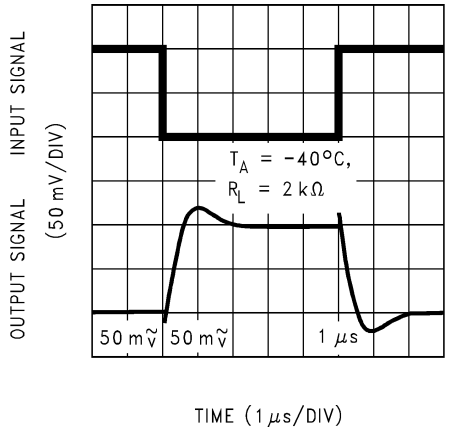


図 5-39. Inverting Small-Signal Pulse Response

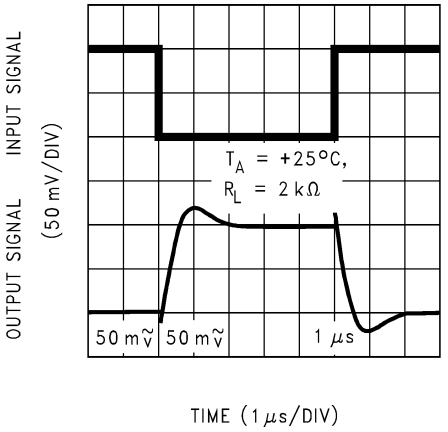


図 5-40. Inverting Small-Signal Pulse Response

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

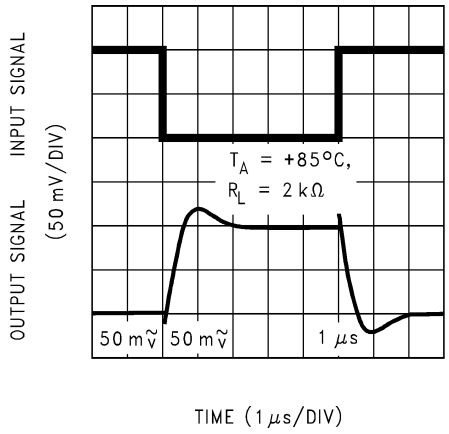


図 5-41. Inverting Small-Signal Pulse Response

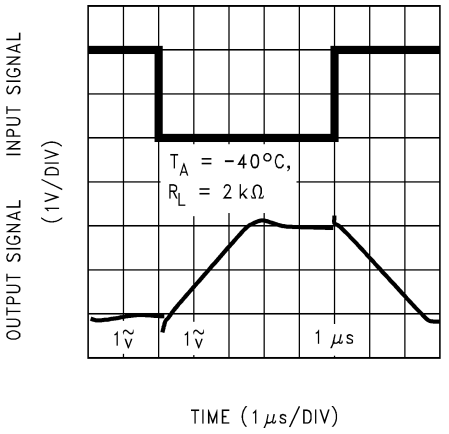


図 5-42. Inverting Large-Signal Pulse Response

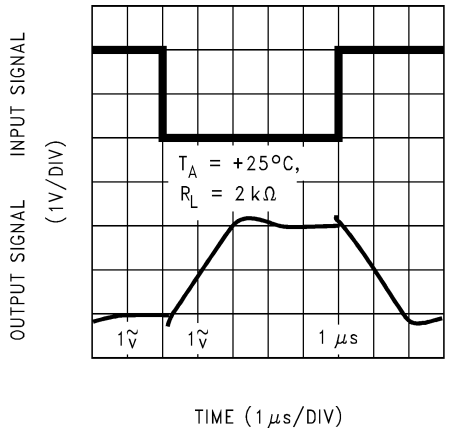


図 5-43. Inverting Large-Signal Pulse Response

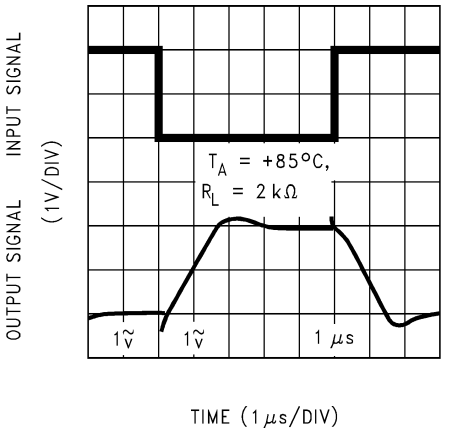


図 5-44. Inverting Large-Signal Pulse Response

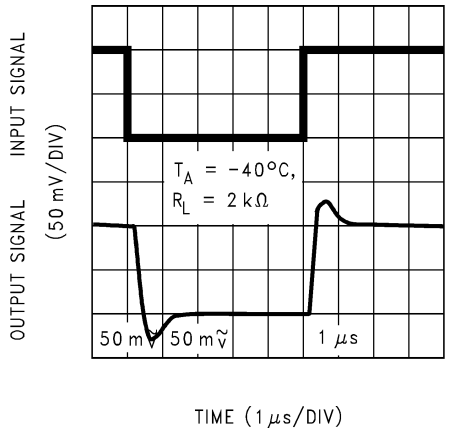


図 5-45. Noninverting Small-Signal Pulse Response

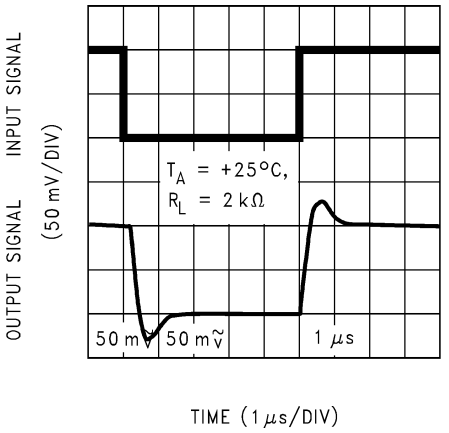


図 5-46. Noninverting Small-Signal Pulse Response

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

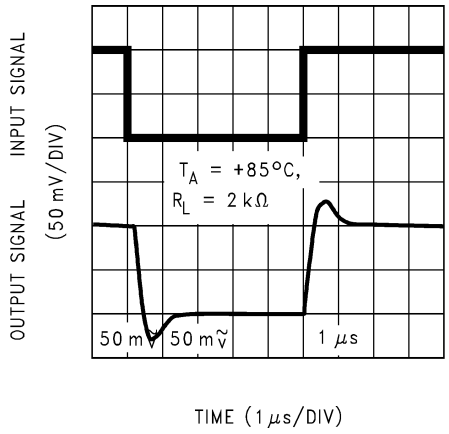


図 5-47. Noninverting Small-Signal Pulse Response

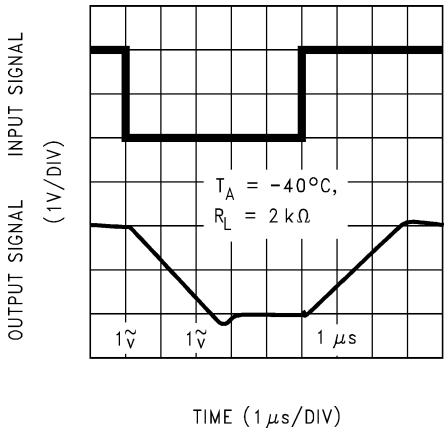


図 5-48. Noninverting Large-Signal Pulse Response

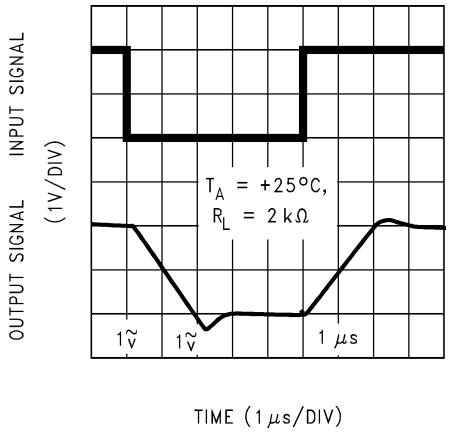


図 5-49. Noninverting Large-Signal Pulse Response

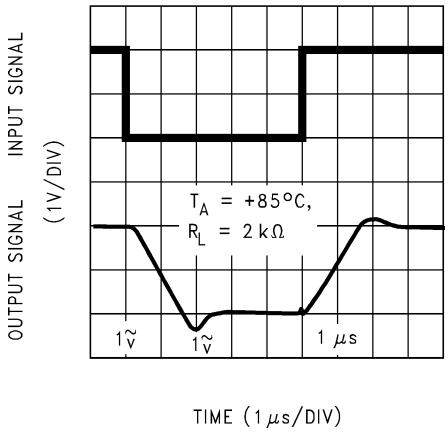


図 5-50. Noninverting Large-Signal Pulse Response

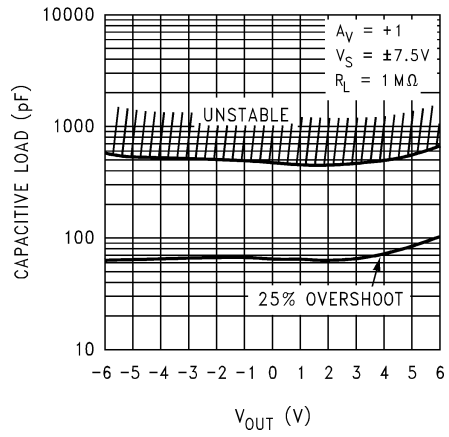


図 5-51. Stability vs Capacitive Load

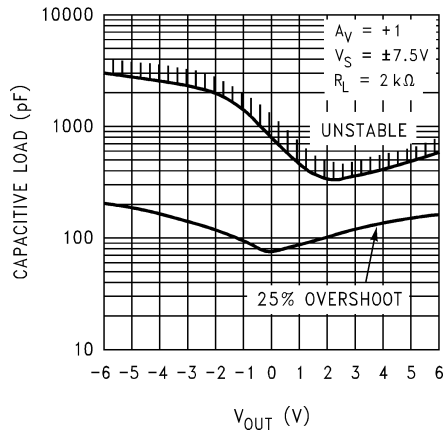


図 5-52. Stability vs Capacitive Load

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

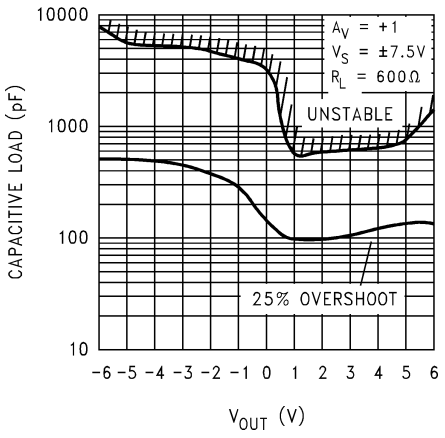


図 5-53. Stability vs Capacitive Load

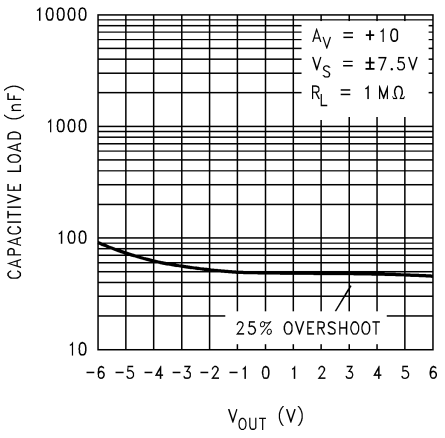


図 5-54. Stability vs Capacitive Load

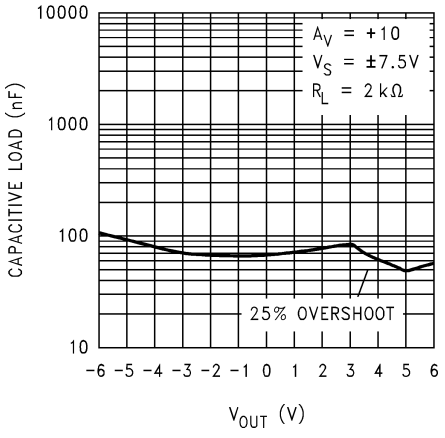


図 5-55. Stability vs Capacitive Load

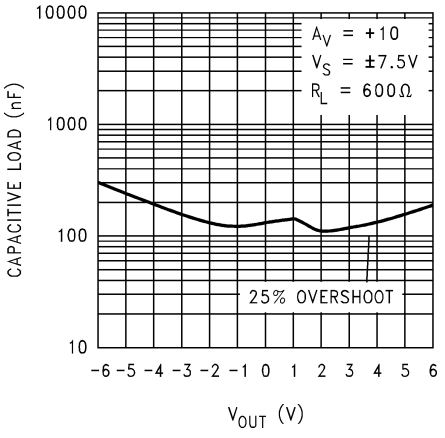


図 5-56. Stability vs Capacitive Load

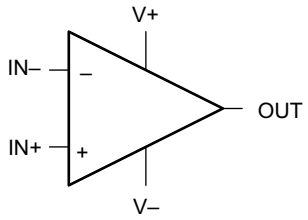
6 Detailed Description

6.1 Overview

The LMC7101Q-Q1 is a single-channel, low-power operational amplifier available in a space-saving SOT-23 package, offering rail-to-rail input and output operation across a wide range of power-supply configurations.

The LMC7101Q-Q1 is also available in a commercial-grade variant, see LMC7101.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Benefits of the LMC7101 Tiny Amplifier

6.3.1.1 Size

The small footprint of the SOT-23-5 packaged tiny amplifier, (0.12in × 0.118in, 3.05mm × 3mm) saves space on printed circuit boards, and enable the design of smaller electronic products. Many customers prefer smaller and lighter products because the designs can contribute to overall weight reduction in vehicles.

6.3.1.2 Height

The 0.056 inches (1.43mm) height of the tiny LMC7101Q-Q1 amplifier makes the device an excellent choice for use in a wide range of circuit boards in which a thin profile is required.

6.3.1.3 Signal Integrity

Signals can pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, the tiny amplifier can be placed closer to the signal source, thus reducing noise pickup and increasing signal integrity. The tiny amplifier can also be placed next to the signal destination, such as a buffer, for the reference of an analog-to-digital converter.

6.3.1.4 Simplified Board Layout

The tiny LMC7101Q-Q1 amplifier can simplify board layout in several ways. Avoid long PCB traces by correctly placing amplifiers instead of routing signals to a dual or quad device. By using multiple tiny amplifiers instead of duals or quads, complex signal routing and possibly crosstalk can be reduced.

6.3.1.5 Low THD

The high open-loop gain of the LMC7101Q-Q1 amplifier helps to achieve very low audio distortion—typically 0.01% at 10kHz with a 10kΩ load at 5V supplies. This makes the tiny amplifier an excellent choice for automotive audio and low-frequency signal-processing applications.

6.3.1.6 Low Supply Current

The typical 0.5mA supply current of the LMC7101Q-Q1 can help improve thermal performance on high density circuit boards, and can allow the reduction of the overall board size in some applications.

6.3.1.7 Wide Voltage Range

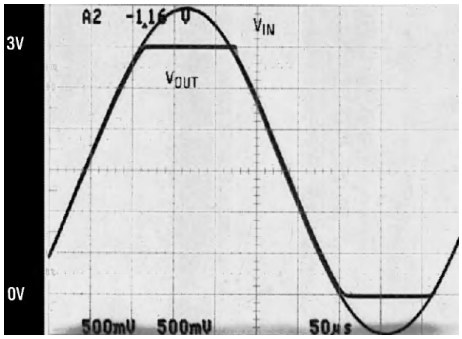
The LMC7101 is characterized at 15V, 5V and 3V. Performance data is provided at these popular voltages. This wide voltage range makes the LMC7101Q-Q1 a good choice for devices where the supply voltage can vary.

6.4 Device Functional Modes

6.4.1 Input Common-Mode Voltage Range

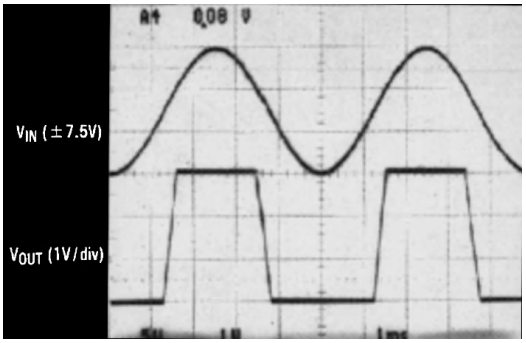
The LMC7101Q-Q1 does not exhibit phase inversion when an input voltage exceeds the negative supply voltage. 図 6-1 shows an input voltage exceeding both supplies with no resulting phase inversion of the output.

The absolute maximum input voltage is 300mV beyond either rail at room temperature. Voltages greatly exceeding this maximum rating, as in 図 6-2, can cause excessive current to flow in or out of the input pins, thus adversely affecting reliability.



The input voltage signal exceeds the amplifier power supply voltage with no output phase inversion.

図 6-1. Input Voltage



The ±7.5V input signal greatly exceeds the 3V supply in 図 6-3 causing no phase inversion due to R_I.

図 6-2. Input Signal

Applications that exceed this rating must externally limit the maximum input current to ±5mA with an input resistor as shown in 図 6-3.

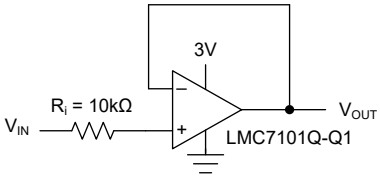


図 6-3. R_I Input Current Protection for Voltages Exceeding the Supply Voltage

7 Application and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

7.1 Application Information

7.1.1 Rail-to-Rail Output

The approximate output resistance of the LMC7101Q-Q1 is 180Ω sourcing and 130Ω sinking at V_S = 3V and 110Ω sourcing and 80Ω sinking at V_S = 5V. Using the calculated output resistance, maximum output voltage swing can be estimated as a function of load.

7.1.2 Capacitive Load Tolerance

The LMC7101Q-Q1 can typically directly drive a 100pF load with V_S = 15V at unity gain without oscillating. The unity gain follower is the most sensitive configuration. Direct capacitive loading reduces the phase margin of operational amplifiers. The combination of the output impedance and the capacitive load of the operational amplifier induces phase lag, which results in either an underdamped pulse response or oscillation.

Capacitive load compensation can be accomplished using resistive isolation as shown in 図 7-1. This simple technique is useful for isolating the capacitive input of multiplexers and A/D converters.

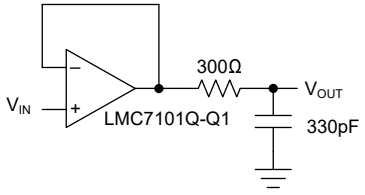


図 7-1. Resistive Isolation of a 330pF Capacitive Load

7.1.3 Compensating for Input Capacitance When Using Large Value Feedback Resistors

When using very large value feedback resistors, (usually >500 kΩ) the large feed back resistance can react with the input capacitance due to transducers, photo diodes, and circuit board parasitics to reduce phase margins.

The effect of input capacitance can be compensated for by adding a feedback capacitor. The feedback capacitor (as in 図 7-2), C_f is first estimated by 式 1 and 式 2, which typically provides significant overcompensation.

$$\frac{1}{2\pi R_1 C_{IN}} \geq \frac{1}{2\pi R_2 C_f} \quad (1)$$

$$2\pi R_1 C_{IN} \leq 2\pi R_2 C_f \quad (2)$$

Printed circuit board stray capacitance can be larger or smaller than that of a breadboard, so the actual optimum value for C_F can be different. The values of C_F must be checked on the actual circuit.

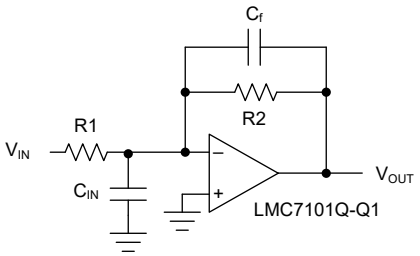


図 7-2. Canceling the Effect of Input Capacitance

7.2 Typical Application

図 7-3 shows a high input impedance noninverting circuit. This circuit gives a closed-loop gain equal to the ratio of the sum of R1 and R2 to R1 and a closed-loop 3dB bandwidth equal to the amplifier unity-gain frequency divided by the closed-loop gain. This design has the benefit of a very high input impedance, which is equal to the differential input impedance multiplied by loop gain (open loop gain / closed loop gain). In dc-coupled applications, input impedance is not as important as input current and the voltage drop across the source resistance. The amplifier output can go into saturation if the input is allowed to float, which can be important if the amplifier must be switched from source to source.

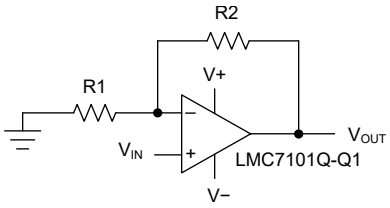


図 7-3. Example Application

7.2.1 Design Requirements

For this example application, the supply voltage is 5V, and 100 × ±5% of noninverting gain is necessary. The signal input impedance is approximately 10kΩ.

7.2.2 Detailed Design Procedure

Use the equation for a noninverting amplifier configuration; G = 1 + R2 / R1, set R1 to 10kΩ, and R2 to 99 × R1, which is 990kΩ. Replacing the 990kΩ resistor with a more readily available 1MΩ resistor results in a gain of 101, which is within the desired gain tolerance. The gain-frequency characteristic of the amplifier and the feedback network must be such that oscillation does not occur. To meet this condition, the phase shift through amplifier and feedback network must never exceed 180° for any frequency where the gain of the amplifier and the feedback network is greater than unity. In practical applications, the phase shift must not approach 180° because this is the situation of conditional stability. The most critical case occurs when the attenuation of the feedback network is zero.

7.2.3 Application Curve

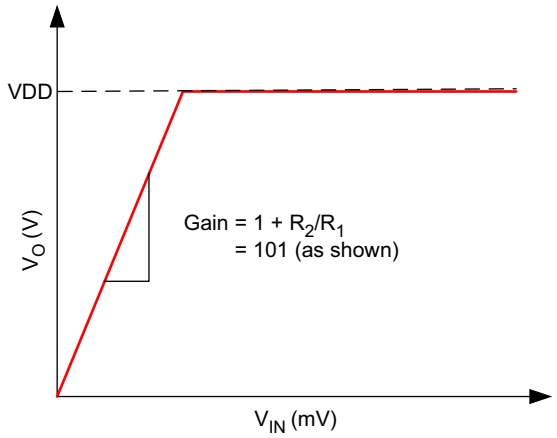


図 7-4. Output Response

7.3 Power Supply Recommendations

For proper operation, the power supplies must be decoupled. For supply decoupling, TI recommends placing 10nF to 1µF capacitors as close as possible to the operational-amplifier power supply pins. For single supply configurations, place a capacitor between the V+ and V− supply pins. For dual supply configurations, place one capacitor between V+ and ground, and place a second capacitor between V− and ground. Bypass capacitors must have a low ESR of less than 0.1Ω.

7.4 Layout

7.4.1 Layout Guidelines

Care must be taken to minimize the loop area formed by the bypass capacitor connection between supply pins and ground. A ground plane underneath the device is recommended; any bypass components to ground must have a nearby via to the ground plane. The optimum bypass capacitor placement is closest to the corresponding supply pin. Use of thicker traces from the bypass capacitors to the corresponding supply pins can lower the power-supply inductance and provide a more stable power supply.

The feedback components must be placed as close as possible to the device to minimize stray parasitics.

7.4.2 Layout Example

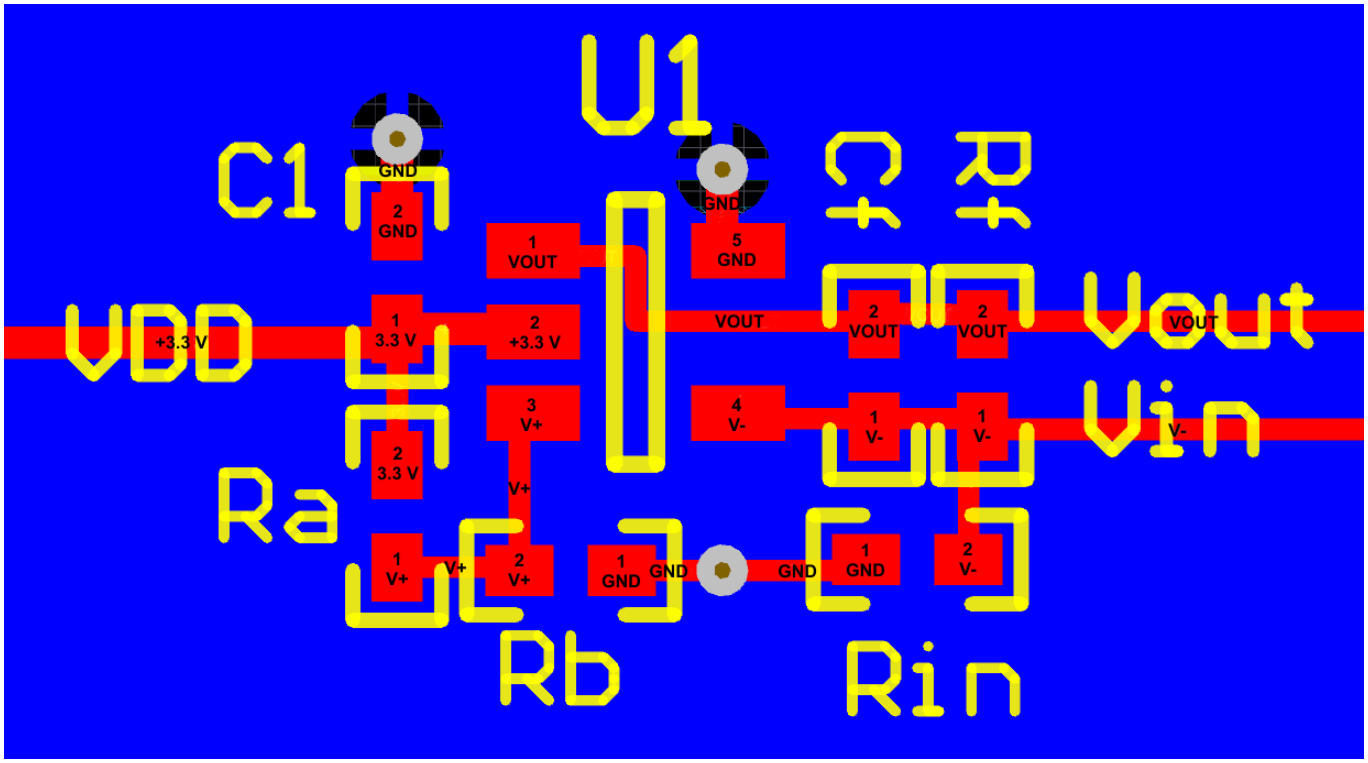


図 7-5. LMC7101Q-Q1 Example Layout

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *LMC66x CMOS Dual Operational Amplifiers* data sheet
- Texas Instruments, *RES11A Matched, Thin-Film Resistor Dividers With 1kΩ Inputs* data sheet

8.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。 変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

8.3 サポート・リソース

テキサス・インスツルメンツ E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計で必要な支援を迅速に得ることができます。

リンクされているコンテンツは、各寄稿者により「現状のまま」提供されるものです。これらはテキサス・インスツルメンツの仕様を構成するものではなく、必ずしもテキサス・インスツルメンツの見解を反映したものではありません。テキサス・インスツルメンツの使用条件を参照してください。

8.4 Trademarks

テキサス・インスツルメンツ E2E™ is a trademark of Texas Instruments.
すべての商標は、それぞれの所有者に帰属します。

8.5 静電気放電に関する注意事項

この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.6 用語集

テキサス・インスツルメンツ用語集　　この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision G (September 2015) to Revision H (January 2025)	Page
• LMC7101 商用デバイスを新しい SBOSAL2 データシートに移動	1
• 「特長」を更新	1
• *「概要」を更新*	1
• Updated pin diagram figure and pin names in *Pin Configuration and Functions*	2
• Deleted Machine model (MM) from *ESD Ratings*	3
• Changed temperature test conditions from junction temperature, T_J to ambient temperature, T_A throughout	3
• Updated *Thermal Information*	3
• Updated formatting across all *Electrical Characteristics*	4
• Updated parameter names to be consistent with modern data sheets	4
• Added missing input offset voltage drift temperature condition in all *Electrical Characteritics*	4
• Updated temperature range conditions in input bias current and input offset current in all Electrical Characteristics	4

- Changed input common-mode voltage condition from CMRR ≥ 50dB to CMRR ≥ 47dB....4
- Changed CMRR MIN from 50dB to 47dB....4
- Deleted footnotes 1 and 2 in all *Electrical Characteristics* 4
- Changed input common-mode voltage condition from CMRR > 50dB to CMRR > 47dB....5
- Changed CMRR MIN from 60dB to 47dB and TYP from 74dB to 70dB 5
- Changed CMRR MIN from 60dB to 52dB and TYP from 82dB to 75dB....6
- Changed CMRR MIN for T_A = –40°C to +125°C from 60dB to 51dB and TYP from 82dB to 74dB....6
- Changed input common-mode voltage test condition from (V+) = 5V to (V+) = 15V....7
- Changed CMRR MIN from 65dB to 62dB....7
- Deleted Figures 6, 11, 14, 17, 20, 23, and 37....9
- Added Figure 5-6....9
- Added Figures 5-21 and 5-25....13
- Updated description text in *Size* 20
- Updated Figure 7-3, *Example Application* to show correct noninverting circuit....23

Changes from Revision F (March 2013) to Revision G (September 2015) **Page**

- 「ピン構成および機能」、「ESD 定格」、「機能説明」、「デバイスの機能モード」、「アプリケーションと実装」、「電源に関する推奨事項」、「レイアウト」、「デバイスおよびドキュメントのサポート」、「メカニカル、パッケージ、および注文情報」の各セクションを追加 1

Changes from Revision E (March 2013) to Revision F (March 2013) **Page**

- Changed layout of National Semiconductor Data Sheet to TI format....23

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

重要なお知らせと免責事項

テキサス・インスツルメンツは、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、テキサス・インスツルメンツ製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した テキサス・インスツルメンツ製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている テキサス・インスツルメンツ製品を使用するアプリケーションの開発の目的でのみ、テキサス・インスツルメンツはその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。テキサス・インスツルメンツや第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、テキサス・インスツルメンツおよびその代理人を完全に補償するものとし、テキサス・インスツルメンツは一切の責任を拒否します。

テキサス・インスツルメンツの製品は、テキサス・インスツルメンツの販売条件、または ti.com やかかる テキサス・インスツルメンツ製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。テキサス・インスツルメンツがこれらのリソースを提供することは、適用されるテキサス・インスツルメンツの保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、テキサス・インスツルメンツはそれらに異議を唱え、拒否します。

郵送先住所:Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LMC7101QM5/NOPB	Obsolete	Production	SOT-23 (DBV) | 5	-	-	Call TI	Call TI	-40 to 125	AT6A
LMC7101QM5X/NOPB	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	Call TI | Sn	Level-1-260C-UNLIM	-40 to 125	AT6A
LMC7101QM5X/NOPB.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	AT6A
LMC7101QM5X/NOPB.B	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	AT6A

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

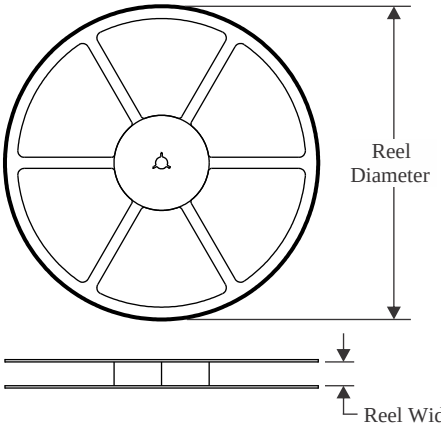
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

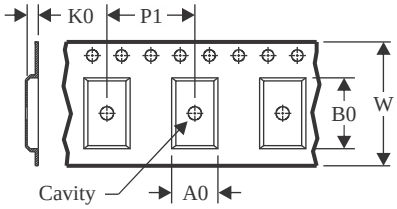
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

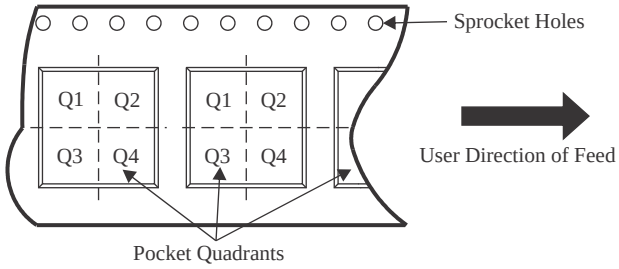


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

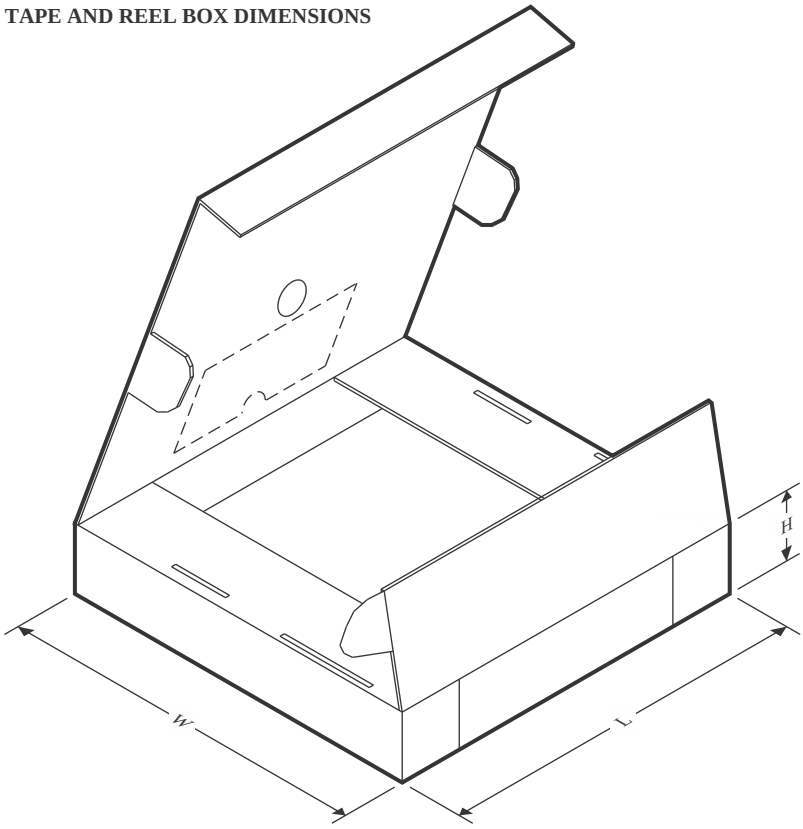
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMC7101QM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMC7101QM5X/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

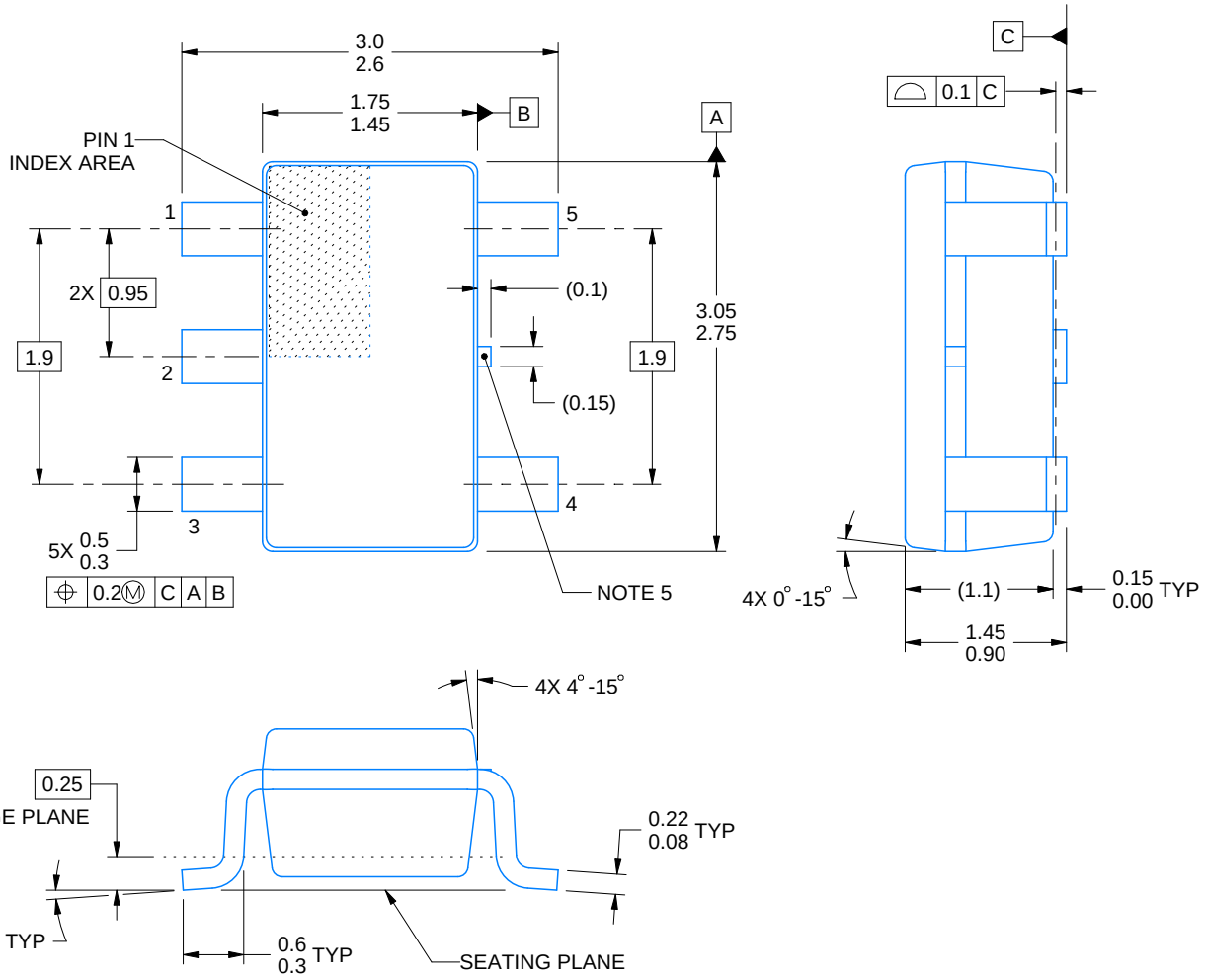
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMC7101QM5X/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LMC7101QM5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

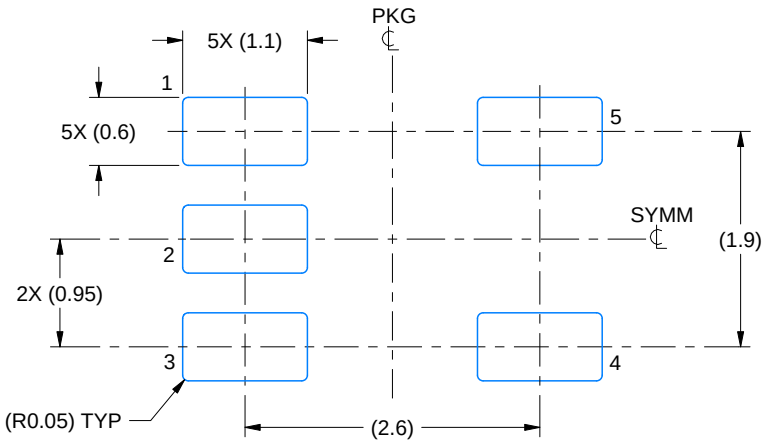
SMALL OUTLINE TRANSISTOR



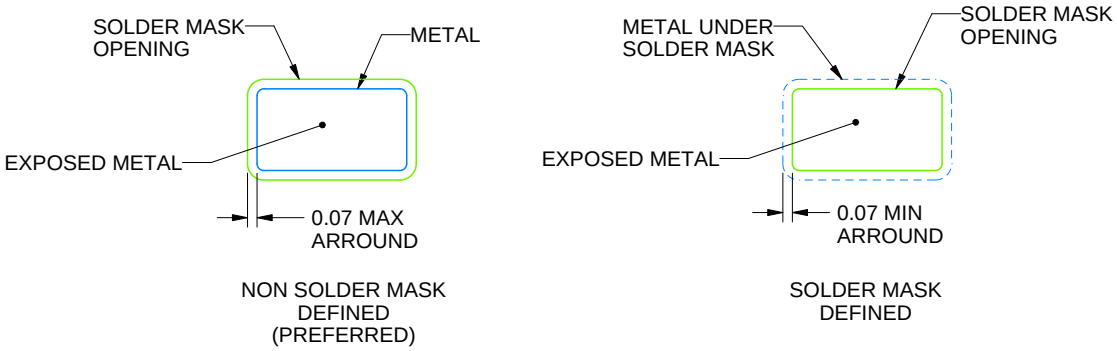
4214839/K 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

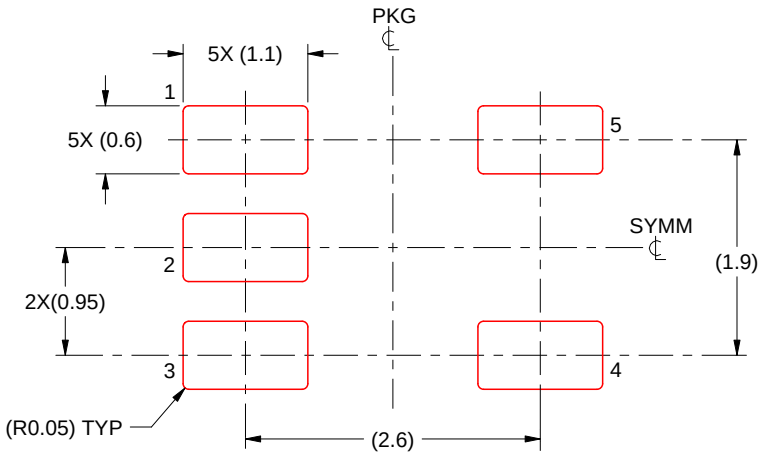


SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

重要なお知らせと免責事項

TI は、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプリケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TI の製品は、 TI の販売条件 、 TI の総合的な品質ガイドライン 、 ti.com または TI 製品などに関連して提供される他の適用条件に従い提供されます。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありません。 TI がカスタム、またはカスタマー仕様として明示的に指定していない限り、TI の製品は標準的なカタログに掲載される汎用機器です。

お客様がいかなる追加条項または代替条項を提案する場合も、TI はそれらに異議を唱え、拒否します。

最終更新日：2025 年 10 月